EQ-733L

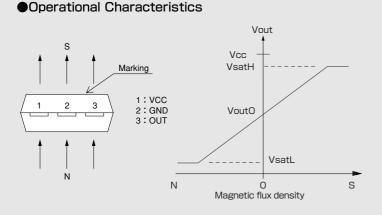
Shipped in bulk(500pcs/Pack)

EQ-733L is composed of an InAs Quantum Well Hall Element and a signal processing IC chip in a package Notice: It is requested to read and accept "IMPORTANT NOTICE" written on the back of the front cover of this catalogue.

Features

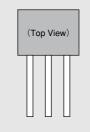
- Analog output which proportional to the magnetic field strength and pole.
- Magnetic sensitivity 20mV/mT(typ.)
- Supply voltage from 3.0V to 5.5V at single power supply
- Operating temperature range -40°C~100°C
- Ratio-metric analog output
- 3pin surface mount plastic package
- Quick response 1 μ s
- (when the rise-up time of magnetic field is rather than $1 \mu s$)
- Low output noise voltage 2mVp-p





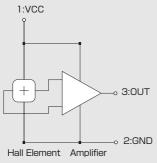
Pin and functions

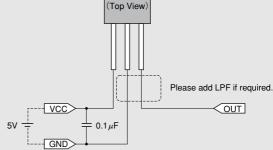
Application Circuit



| Pin No. | Pin name | Function |
|---------|-------------|--------------|
| 1 | VCC | Power supply |
| 2 | 2 GND Groun | |
| 3 | OUT | Output |

Functional Block Diagram





Recommend operating conditions

| parameter | symbol | min | typ | max | unit |
|----------------|--------|------|-----|------|------|
| Supply voltage | Vcc | 3.0 | 5.0 | 5.5 | V |
| output current | Іоит | -1.0 | | 1.0 | mA |
| output load | CL | | | 1000 | pF |

●Absolute Maximum Ratings (Ta=25°C)

| parameter | symbol | specification | unit |
|----------------------------------|-----------------|---------------------|------|
| Supply voltage | V _{CC} | $-0.3 \sim 6$ | V |
| output current | Iout | ±1.2 ^(*) | mA |
| operating ambient temperature | Topr | <i>−</i> 40 ~ 100 | °C |
| Storage ambient temperature | Tstg | −40 ~ 125 | Ĵ |

(*) Vcc=5V

ASAHI KASEI MICRODEVICES

Electric characteristics (TA=25°C, Vcc=5V)

| V _{CC} -0.3 0 of output voltage. output voltage. | 260 | 12 V _{CC} 0.3 | mA V V kHz |
|---|---|------------------------------|--|
| of output voltage. output voltage. | 260 | | V |
| of output voltage. output voltage. | | 0.3 | - |
| output voltage. | | | kHz |
| output voltage. | | | |
| μs) | 1 | | μs |
| | | | |
| | 2 | | μs |
| output voltage. | 0.3 | | μs |
| | 2 | | mVp-p |
| | age under to 2µs. age under to 2µs of output voltage. f output voltage. µs) | to 2μs. | to 2μs. 2 uge under 2 of output voltage. 0.3 |

%1mT = 10Gauss

(*1&2) Design target at 25°C

Magnetic characteristics (TA=25°C, Vcc=5V)

| Parameter | Symbol | Conditions | | Тур | Max | Unit |
|-----------------------------|-------------------|---|------|-----|------|-------|
| Sensitivity ^(*3) | V _h | B=0, \pm 41mT with no load | 17 | 20 | 23 | mV/mT |
| Quiescent voltage | V _{OUT0} | B=0mT | 2.45 | 2.5 | 2.55 | V |
| Linearity ^(*4) | ρ | $B=0mT (I_{OUT}=0mA)$ $B=\pm50mT (I_{OUT}=\pm1mA)$ | -0.5 | | 0.5 | %F.S. |

(*3) See Characteristic Definitions section

(*4) See Characteristic Definitions section

Characteristic Definitions

①Magnetic sensitivity Vh (mV/mT)

Magnetic sensitivity is defined as the slope of the straight line obtained from three points, Quiescent voltage Vouto, Vout (+B), Vout (-B) (B is described in measurement condition), by the least square approximation.

②Linearity ρ (%F.S.)

Linearity is defined as the ratio of a error voltage against FULLSCALE. Where error voltage is calculate as the difference from the straight line obtained from three points, Quiescent voltage Vouto, Vout (+B), Vout (-B) (B and Output current are described in measurement condition shown below), by the least square approximation.

- $\langle Condition \rangle$:0mT applied, lout = 0mA
- +BmT applied : IOUT=+1.0mA (Draw out from output) ut)

$$-BmT applied : Iout = -1.0mA (Draw in to output)
\rho = \frac{V_{out}(B) - \{V_h \times B + V_{int}\}}{V_{out}(B) - \{V_h \times B + V_{int}\}} \times 100$$

$$= \frac{1}{V_{out}(+B) - V_{out}(-B)} \times 10$$

Where FULLSCALE(F.S.) is defied as Vout (+B), Vout (-B), Vint is y-intercepts of the line obtained in the Definition of Magnetic sensitivity.

③Error in Ratiometric of Magnetic sensitivity and Error in Ratiometric of quiescent voltage

Error in ratiometric is defined as the ratio of the variation of sensitivity and guiescent voltage at 3V and 5V as following equations..

$$V_{h-R} = \frac{\frac{V_{h}(V_{CC}=3V)}{V_{h}(V_{CC}=5V)} - \frac{3}{5}}{\frac{3}{5}} \times 100 \quad V_{OUT0-R} = \frac{\frac{V_{OUT0}(V_{CC}=3V)}{V_{OUT0}(V_{CC}=5V)} - \frac{3}{5}}{\frac{3}{5}} \times 100$$

%1mT = 10Gauss

●Ratio-metric characteristics (TA=25℃)

| Parameter | Symbol | Conditions | min | Тур | Max | Unit |
|---|---------------------|-----------------------------|-----|-----|-----|------|
| Error in Ratiometric of Magnetic sensitivity ^(*5) | V _{h-R} | B=0 \pm 41mT with no load | -3 | | 3 | % |
| Error in Ratiometric of Quiescent voltage ^(*5) | V _{OUT0-R} | B=0mT | -3 | | 3 | % |

(*5) See Characteristic Definitions section

%1mT = 10Gauss

(4) Response time $t_{RES}(\mu s)$

Response time is defined as the time from the 90% reach point of input magnetic field rise up to the 90% reach point of output voltage rise up

(5)Output rise time, Output fall time trise, trall (μ s)

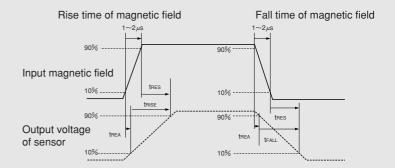
Output rise up time is defined as the time from the 10% point to the 90% point of output voltage under a pulse like magnetic field input shown below.

Output fall down time is defined as the time from the 90% point to the 10% point of output voltage under a pulse like magnetic field input shown below.

(6) Output delay time $\text{treac}(\mu s)$

Output delay time is defined as the time from the 10% point in rise up(90% point in fall down) of input magnetic field to the 10% point in rise up(90% point in fall down) of output voltage under a pulse like magnetic field input shown below..

Relations of the input Magnetic field and tres_trise_trall, treac

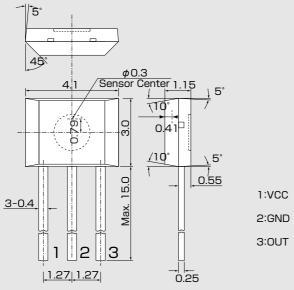


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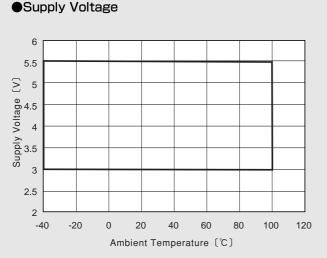
•This product contains galium arsenide(GaAs).Handling and discarding precsutions required.

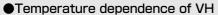
Package (Unit:mm)

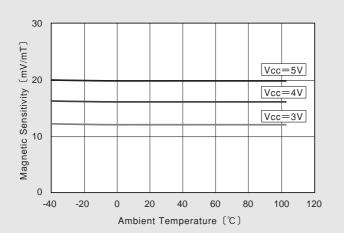


Note1) The sensor center is located within the ϕ 0.3mm circle.

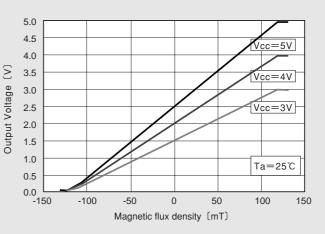
Note2) The metal portions on the package side (support lead) are connected to the internal circuits. The support lead should be isolate from the external circuit and the other support lead.

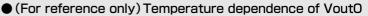


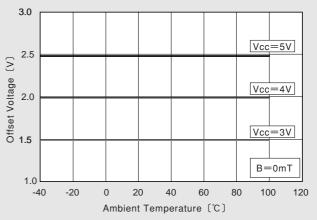




Operational Characteristics







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